



MMBT4403

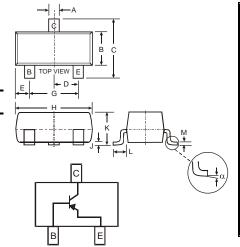
PNP SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

- **Epitaxial Planar Die Construction**
- Complementary NPN Type Available (MMBT4401)
- Ideal for Medium Power Amplification and Switching
- Lead, Halogen and Antimony Free, RoHS Compliant "Green" Device (Notes 2 and 3)

Mechanical Data

- Case: SOT-23
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe)
- Terminal Connections: See Diagram Marking Information: See Page 4 Ordering Information: See Page 4
- Weight: 0.008 grams (approximate)



	SOT-23										
Dim	Min	Max									
Α	0.37	0.51									
В	1.20	1.40									
С	2.30	2.50									
D	0.89	1.03									
Е	0.45	0.60									
G	1.78	2.05									
Ŧ	2.80	3.00									
J	0.013	0.10									
K	0.903	1.10									
L	0.45	0.61									
М	0.085	0.180									
α	0°	8°									
All Dimensions in mm											

Maximum Ratings @TA = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-40	V
Collector-Emitter Voltage	V _{CEO}	-40	V
Emitter-Base Voltage	V _{EBO}	-5.0	V
Collector Current - Continuous (Note 1)	lc	-600	mA
Power Dissipation (Note 1)	P _D	300	mW
Thermal Resistance, Junction to Ambient (Note 1)	$R_{\theta JA}$	417	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes:

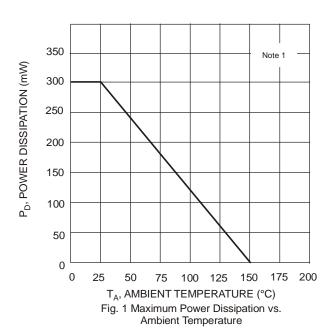
- Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- No purposefully added lead. Halogen and Antimony Free.
- Product manufactured with Data Code V9 (week 33, 2008) and newer are built with Green Molding Compound. Product manufactured prior to Date Code V9 are built with Non-Green Molding Compound and may contain Halogens or Sb₂O₃ Fire Retardants.

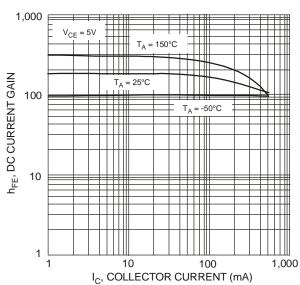


Electrical Characteristics @T_A = 25°C unless otherwise specified

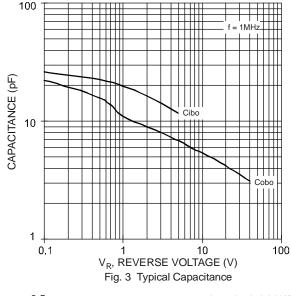
Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 4)					
Collector-Base Breakdown Voltage	V _{(BR)CBO}	-40	_	V	$I_C = -100 \mu A, I_E = 0$
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	-40	_	V	$I_C = -1.0 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	-5.0	_	V	$I_E = -100 \mu A, I_C = 0$
Collector Cutoff Current	I _{CEX}	_	-100	nA	$V_{CE} = -35V, V_{EB(OFF)} = -0.4V$
Base Cutoff Current	I _{BL}		-100	nA	$V_{CE} = -35V, V_{EB(OFF)} = -0.4V$
ON CHARACTERISTICS (Note 4)					
DC Current Gain	h _{FE}	30 60 100 100 20	 300 		$\begin{split} I_{C} &= -100 \mu A, \ V_{CE} = -1.0 V \\ I_{C} &= -1.0 m A, \ V_{CE} = -1.0 V \\ I_{C} &= -10 m A, \ V_{CE} = -1.0 V \\ I_{C} &= -150 m A, \ V_{CE} = -2.0 V \\ I_{C} &= -500 m A, \ V_{CE} = -2.0 V \end{split}$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}		-0.40 -0.75	٧	$I_C = -150$ mA, $I_B = -15$ mA $I_C = -500$ mA, $I_B = -50$ mA
Base-Emitter Saturation Voltage	V _{BE(SAT)}	-0.75 —	-0.95 -1.30	٧	$I_C = -150$ mA, $I_B = -15$ mA $I_C = -500$ mA, $I_B = -50$ mA
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	C _{obo}		8.5	pF	$V_{CB} = -10V$, $f = 1.0MHz$, $I_E = 0$
Input Capacitance	C _{ibo}	_	30	pF	$V_{EB} = -0.5V$, $f = 1.0MHz$, $I_C = 0$
Input Impedance	h _{ie}	1.5	15	kΩ	
Voltage Feedback Ratio	h _{re}	0.1	8.0	x 10 ⁻⁴	V _{CE} = -10V, I _C = -1.0mA,
Small Signal Current Gain	h _{fe}	60	500		f = 1.0kHz
Output Admittance	h _{oe}	1.0	100	μS	
Current Gain-Bandwidth Product	f⊤	200	_	MHz	$V_{CE} = -10V, I_{C} = -20mA,$ f = 100MHz
SWITCHING CHARACTERISTICS					
Delay Time	t _d	_	15	ns	$V_{CC} = -30V, I_{C} = -150mA,$
Rise Time	t _r	_	20	ns	$V_{BE(off)} = -2.0V, I_{B1} = -15mA$
Storage Time	ts	_	225	ns	$V_{CC} = -30V, I_{C} = -150mA,$
Fall Time	t _f	_	30	ns	$I_{B1} = I_{B2} = -15\text{mA}$

Notes: 4. Short duration pulse test used to minimize self-heating effect.









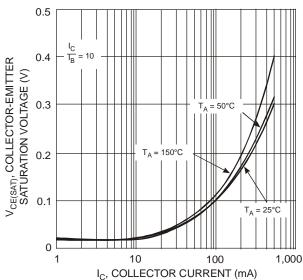
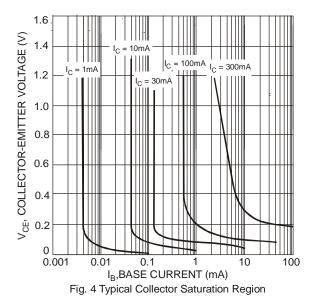


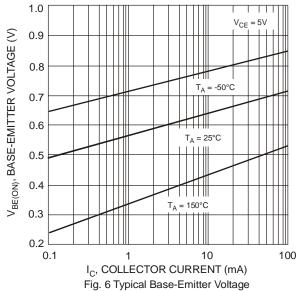
Fig. 5 Typical Collector-Emitter Saturation Voltage

vs. Collector Current

1,000 V_{CE} = 5V V_{CE}

I_C, COLLECTOR CURRENT (mA)
Fig. 7 Typical Gain-Bandwidth Product vs. Collector Current





vs. Collector Current

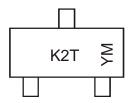


Ordering Information (Note 5)

Device	Packaging	Shipping		
MMBT4403-7-F	SOT-23	3000/Tape & Reel		

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



K2T = Product Type Marking Code YM = Date Code Marking Y = Year ex: N = 2002 M = Month ex: 9 = September

Date Code Key

Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	J	K	L	М	N	Р	R	S	Т	U	V	W	Х	Υ	Z

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

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